

BRIDGE RECTIFIER

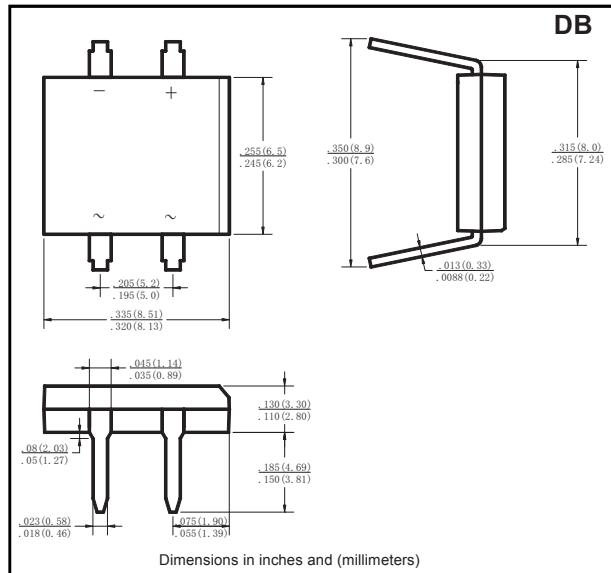
FEATURES

- I_o 2A
- VRM 50V~1000V
- Glass passivated chip
- High surge forward current capability

APPLICATIONS

- General purpose 1 phase Bridge rectifier applications

Outline Dimensions and Mark



ABSOLUTE MAXIMUM RATING & ELECTRICAL CHARACTERISTICS (TA=25 °C)

	SYMBOLS	DB201	DB202	DB203	DB204	DB205	DB206	DB207	UNITS
Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Average Rectified Output Current 60Hz ,Ta=25 60Hz sine wave, R-load ,Ta=25	I_o				2.0				Amps
Surge(Non-Repetitive) Forward Current 60HZ,Tj=25 60HZ sine wave, 1 cycle, Tj=25	I_{FSM}				60				Amps
Current Squared Time $1ms \leq t \leq 8.3ms$ Tj=25 , $1ms \leq t \leq 8.3ms$ Tj=25 , Rating of per diode	I^2T				15				A^2s
Peak Forward Voltage IFM=2.0A, Pulse measurement, Rating of per diode	V_F				1.1				Volts
Peak Reverse Current VRM=VRM, Pulse measurement, Rating of per diode	I_{RRM}				10				μ Amps
Thermal Resistance	Between junction & ambient	$R_{\theta JA}$			68				$^{\circ}C/W$
	Between junction and lead	$R_{\theta JL}$			15				
Operating Temperature Range	T_j				-55 to +150				$^{\circ}C$
Storage Temperature Range	T_{STG}				-55 to +150				$^{\circ}C$

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CHARACTERISTICS (TYPICAL)

FIG1:Io-Ta Curve

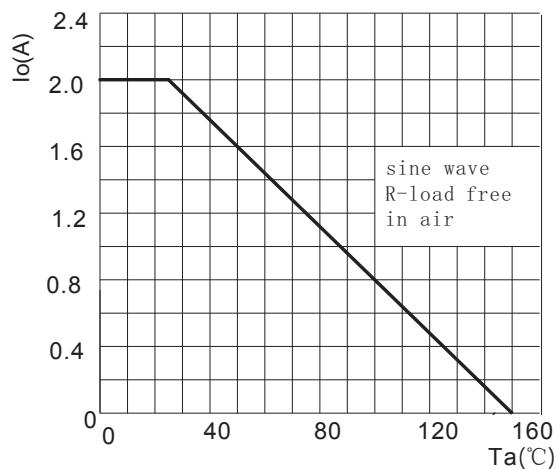


FIG2: Surge Forward Current Capability

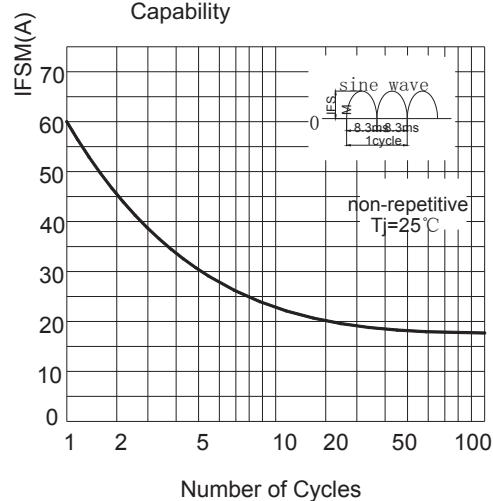


FIG3: Forward Voltage

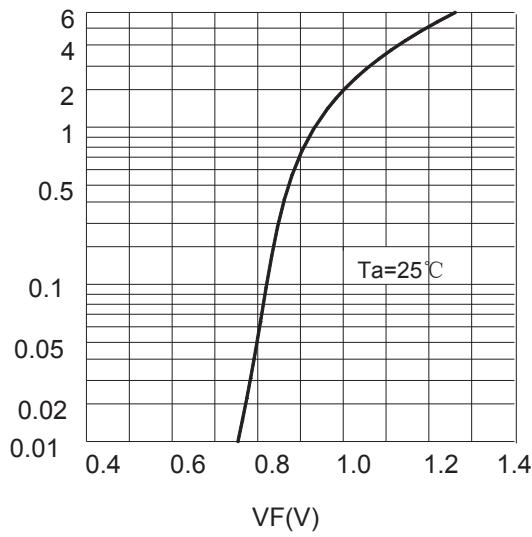
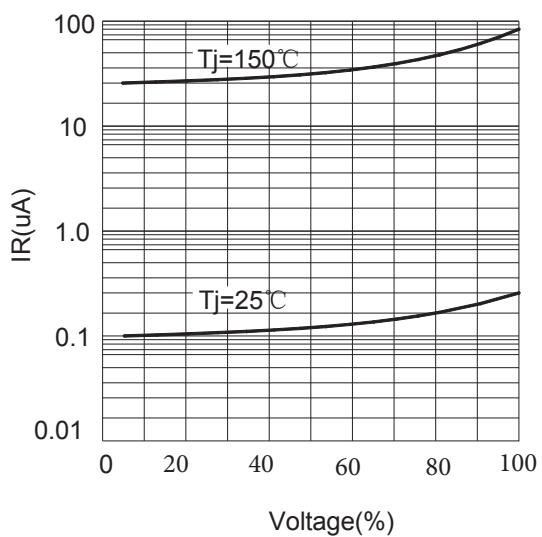


FIG4: Typical Reverse Characteristics



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All product, product specifications and data are subject to change without notice to improve reliability, function or design or otherwise.